NSN 5961-01-526-6665

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-526-6665 **Overall Length:** 3.700 inches **Overall Height:** 1.180 inches **Overall Width:** 1.890 inches **End Application:** Power unit, 2kva, ups 832-01a, 832-01b. Power unit, 3kva, ups 833-01d, 833-01c, 833-01b. Power unit, 2.4 kw, dc 831-01. **Mounting Facility Quantity: Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole Voltage Rating In Volts Per Characteristic: 600.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor **Current Rating Per Characteristic:** 150.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 watts small-signal input power, common-collector megawatts all transistor **Special Features:** Low drive power, low vce, discrete super-fast recovery (70ns) free wheel diode, isolated baseplate for easy heat sinking. **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure:** Demilitarization: